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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No. 09/920,978
Filing Date August 1, 2001
Inventor Shane J. Trapp
Assignee Micron Technology, Inc.
Group Art Unit 2813
Examiner David S. Blum
Attorney's Docket No. MI22-1674
Title: Method of Forming Integrated Circuitry and Method of Forming Shallow
Trench Isolation in a Semiconductor Substrate

RESPONSE TO MARCH 1, 2002 OFFICE ACTION

To: Box Non-Fee Amendment
Assistant Commissioner for Patents
Washington, D.C. 20231

VIA FACSIMILE

From: Mark S. Matkin (Tel. 509-624-4276; Fax 509-838-3424)
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Spokane, WA 99201-3828

Responsive to the Office Action dated March 1, 2002, Applicant amends
and remarks as follows:

FAX COPY RECEIVED**AMENDMENTS****APR 26 2002****In the Specification**

TECHNOLOGY CENTER 2800

Please replace the paragraph beginning at line 5 on page 2 with the
following clean replacement paragraph in accordance with 37 CFR
§ 1.121(b)(1)(ii). A marked-up version showing amendments to the
specification paragraph being changed is provided in one or more